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Thank you for your cooperation and understanding,

Ampleon

HF/VHF power MOS transistor

BLF177

FEATURES

- · High power gain
- · Low intermodulation distortion
- · Easy power control
- · Good thermal stability
- · Withstands full load mismatch.

APPLICATIONS

· Designed for industrial and military applications in the HF/VHF frequency range.

DESCRIPTION

Silicon N-channel enhancement mode vertical D-MOS transistor encapsulated in a 4-lead, SOT121B flanged package, with a ceramic cap. All leads are isolated from the flange.

A marking code, showing gate-source voltage (V_{GS}) information is provided for matched pair applications. Refer to the handbook 'General' section for further information.

PIN CONFIGURATION

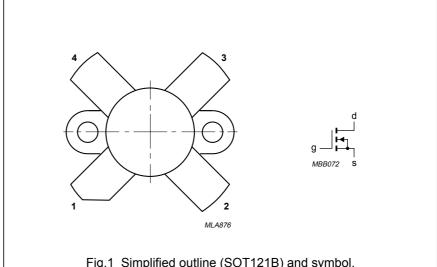


Fig.1 Simplified outline (SOT121B) and symbol.

CAUTION

This product is supplied in anti-static packing to prevent damage caused by electrostatic discharge during transport and handling. For further information, refer to Philips specs.: SNW-EQ-608, SNW-FQ-302A, and SNW-FQ-302B.

PINNING

PIN	DESCRIPTION					
1	drain					
2	source					
3	gate					
4	source					

WARNING

Product and environmental safety - toxic materials

This product contains beryllium oxide. The product is entirely safe provided that the BeO disc is not damaged. All persons who handle, use or dispose of this product should be aware of its nature and of the necessary safety precautions. After use, dispose of as chemical or special waste according to the regulations applying at the location of the user. It must never be thrown out with the general or domestic waste.

QUICK REFERENCE DATA

RF performance at T_h = 25 °C in a common source test circuit.

MODE OF OPERATION	f (MHz)	V _{DS} (V)	P _L (W)	G _p (dB)	η _D (%)	d ₃ (dB)	d ₅ (dB)
SSB class-AB	28	50	150 (PEP)	>20	>35	<-30	<-30
CW class-B	108	50	150	typ. 19	typ. 70	_	_

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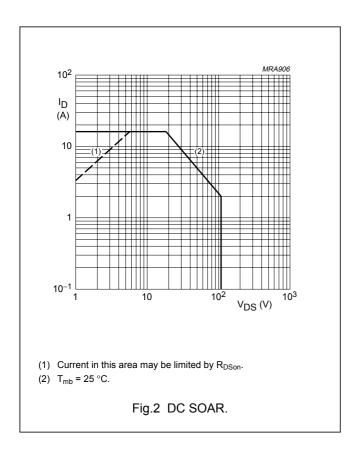
LIMITING VALUES

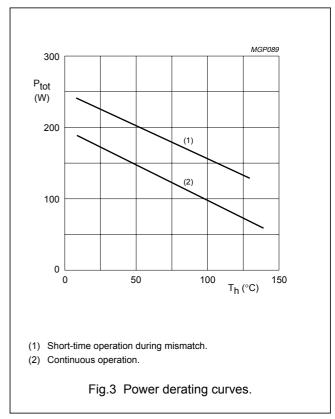
In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DS}	drain-source voltage		_	125	V
V_{GS}	gate-source voltage		_	±20	V
I _D	drain current (DC)		_	16	Α
P _{tot}	total power dissipation	T _{mb} ≤ 25 °C	_	220	W
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	200	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-mb}	thermal resistance from junction to mounting base	max. 0.8	K/W
R _{th mb-h}	thermal resistance from mounting base to heatsink	max. 0.2	K/W





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CHARACTERISTICS

 T_i = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 100 mA; V _{GS} = 0	125	_	_	V
I _{DSS}	drain-source leakage current	V _{GS} = 0; V _{DS} = 50 V	_	_	2.5	mA
I _{GSS}	gate-source leakage current	$V_{GS} = \pm 20 \text{ V}; V_{DS} = 0$	_	_	1	μΑ
V_{GSth}	gate-source threshold voltage	I _D = 50 mA; V _{DS} = 10 V	2	_	4.5	V
ΔV_{GS}	gate-source voltage difference of matched pairs	I _D = 50 mA; V _{DS} = 10 V	_	_	100	mV
9 _{fs}	forward transconductance	I _D = 5 A; V _{DS} = 10 V	4.5	6.2	_	s
R _{DSon}	drain-source on-state resistance	I _D = 5 A; V _{GS} = 10 V	_	0.2	0.3	Ω
I _{DSX}	on-state drain current	V _{GS} = 10 V; V _{DS} = 10 V	_	25	_	Α
C _{is}	input capacitance	V _{GS} = 0; V _{DS} = 50 V; f = 1 MHz	_	480	_	pF
C _{os}	output capacitance	V _{GS} = 0; V _{DS} = 50 V; f = 1 MHz	_	190	_	pF
C _{rs}	feedback capacitance	V _{GS} = 0; V _{DS} = 50 V; f = 1 MHz	_	14	_	pF

V_{GS} group indication

GROUP		IITS /)	GROUP	LIMITS (V)		
	MIN.	MAX.		MIN.	MAX.	
Α	2.0	2.1	0	3.3	3.4	
В	2.1	2.2	Р	3.4	3.5	
С	2.2	2.3	Q	3.5	3.6	
D	2.3	2.4	R	3.6	3.7	
E	2.4	2.5	S	3.7	3.8	
F	2.5	2.6	Т	3.8	3.9	
G	2.6	2.7	U	3.9	4.0	
Н	2.7	2.8	V	4.0	4.1	
J	2.8	2.9	W	4.1	4.2	
K	2.9	3.0	Х	4.2	4.3	
L	3.0	3.1	Y	4.3	4.4	
М	3.1	3.2	Z	4.4	4.5	
N	3.2	3.3				

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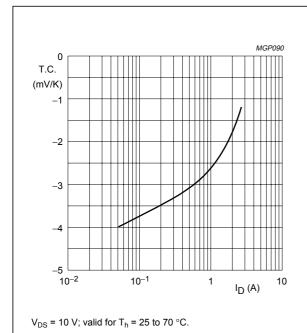
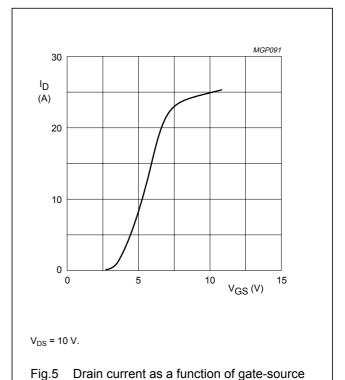
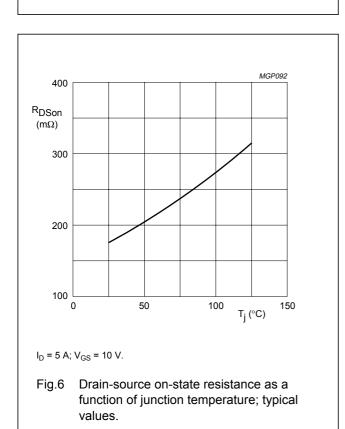
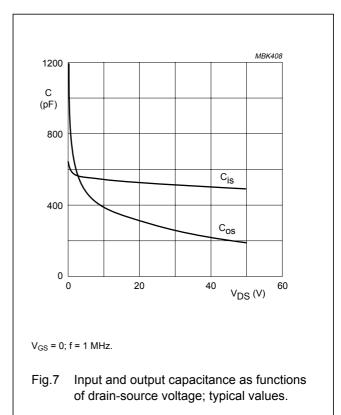


Fig.4 Temperature coefficient of gate-source voltage as a function of drain current; typical values.



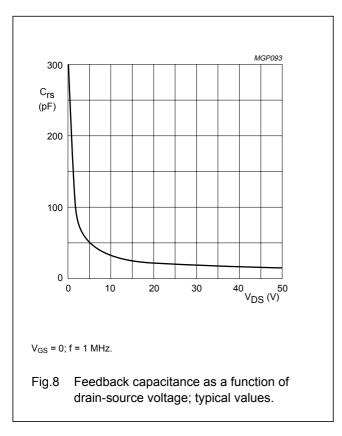
voltage; typical values.





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APPLICATION INFORMATION FOR CLASS-AB OPERATION

RF performance in SSB operation in a common source class-AB test circuit (see Fig.13). T_h = 25 °C; $R_{th\ mb-h}$ = 0.2 K/W; Z_L = 6.25 + j0 Ω ; f_1 = 28.000 MHz; f_2 = 28.001 MHz unless otherwise specified.

MODE OF OPERATION	f (MHz)	V _{DS} (V)	I _{DQ} (A)	P _L (W)	G _p (dB)	η _D (%)	d ₃ (dB) (note 1)	d ₅ (dB) (note 1)
SSB, class-AB	28	50	0.7	20 to 150 (PEP)	>20 typ. 35	>35 typ. 40	<-30 typ35	<-30 typ38

Note

1. Maximum values at drive levels within the specified PEP values for either amplified tone. For the peak envelope power the values should be decreased by 6 dB.

Ruggedness in class-AB operation

The BLF177 is capable of withstanding a load mismatch corresponding to VSWR = 50 through all phases under the following conditions: f = 28 MHz; $V_{DS} = 50 \text{ V}$ at rated output power.

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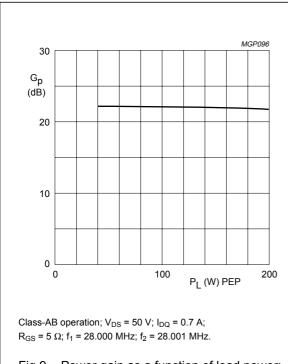
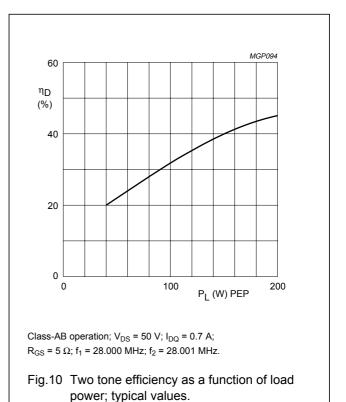
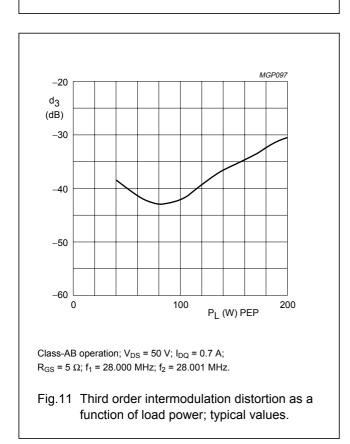
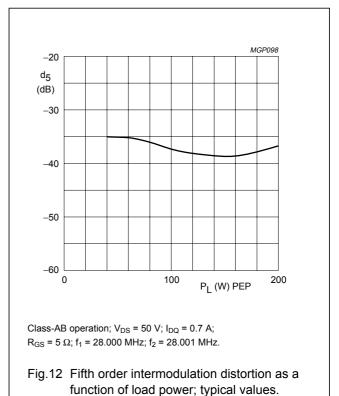


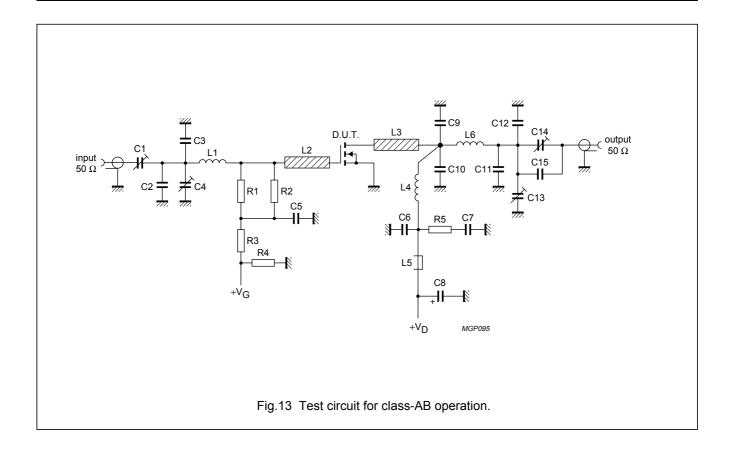
Fig.9 Power gain as a function of load power; typical values.







HF/VHF power MOS transistor



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List of components class-AB test circuit (see Fig.13)

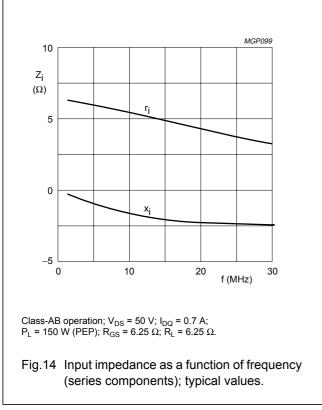
COMPONENT	DESCRIPTION	VALUE	DIMENSIONS	CATALOGUE NO.
C1, C4, C13, C14	film dielectric trimmer	7 to 100 pF		2222 809 07015
C2	multilayer ceramic chip capacitor (note 1)	56 pF		
C3, C11	multilayer ceramic chip capacitor (note 1)	62 pF		
C5, C6	multilayer ceramic chip capacitor	100 nF		2222 852 47104
C7	multilayer ceramic chip capacitor	3 × 100 nF		2222 852 47104
C8	electrolytic capacitor	2.2 μF, 63 V		
C9, C10	multilayer ceramic chip capacitor (note 1)	20 pF		
C12	multilayer ceramic chip capacitor (note 1)	100 pF		
C15	multilayer ceramic chip capacitor (note 1)	150 pF		
L1	5 turns enamelled 0.7 mm copper wire	133 nH	length 4.5 mm; int. dia. 6 mm; leads 2 × 5 mm	
L2, L3	stripline (note 2)	41.1 Ω	length 13 × 6 mm	
L4	7 turns enamelled 1.5 mm copper wire	236 nH	length 12.5 mm; int. dia. 8 mm; leads 2 × 5 mm	
L5	grade 3B Ferroxcube wideband HF choke			4312 020 36642
L6	5 turns enamelled 2 mm copper wire	170 nH	length 11.5 mm; int. dia. 8 mm; leads 2 × 5 mm	
R1, R2	metal film resistor	10 Ω, 1 W		
R2	metal film resistor	10 kΩ, 0.4 W		
R3	metal film resistor	1 MΩ, 0.4 W		
R5	metal film resistor	10 kΩ, 1 W		

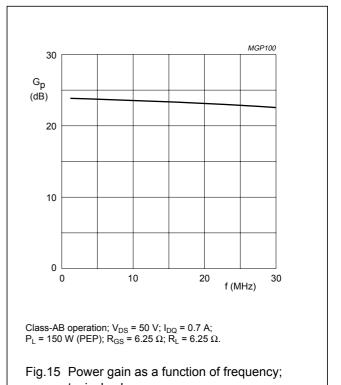
Notes

- 1. American Technical Ceramics (ATC) capacitor, type 100B or other capacitor of the same quality.
- 2. The striplines are on a double copper-clad printed circuit board, with PTFE fibre-glass dielectric (ε_r = 2.2), thickness 1.6 mm (Rogers 5880).

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(series components); typical values. typical values.

APPLICATION INFORMATION FOR CLASS-B OPERATION

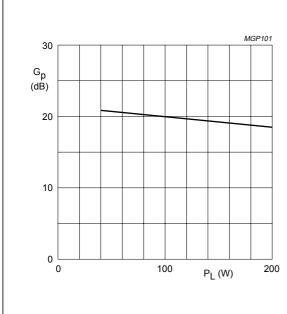
RF performance in CW operation in a common source class-B test circuit (see Fig.19).

 T_{h} = 25 °C; $R_{th\;mb\text{-}h}$ = 0.2 K/W; R_{GS} = 15.8 Ω unless otherwise specified.

MODE OF OPERATION	f	V _{DS}	I _{DQ}	P _L	G _p	η _D
	(MHz)	(V)	(A)	(W)	(dB)	(%)
CW, class-B	108	50	0.1	150	typ. 19	typ. 70

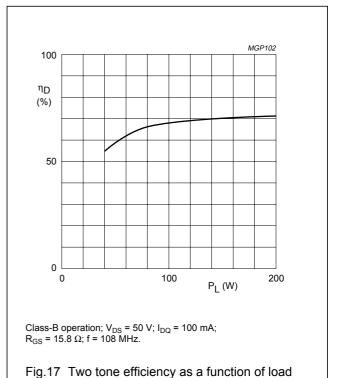
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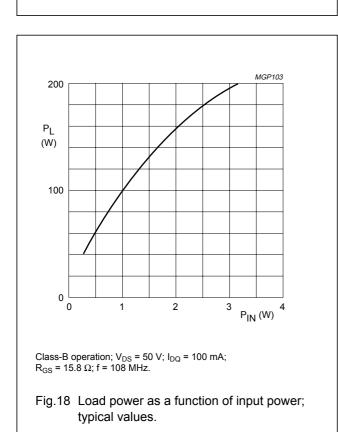


Class-B operation; V_{DS} = 50 V; I_{DQ} = 100 mA; R_{GS} = 15.8 Ω ; f = 108 MHz.

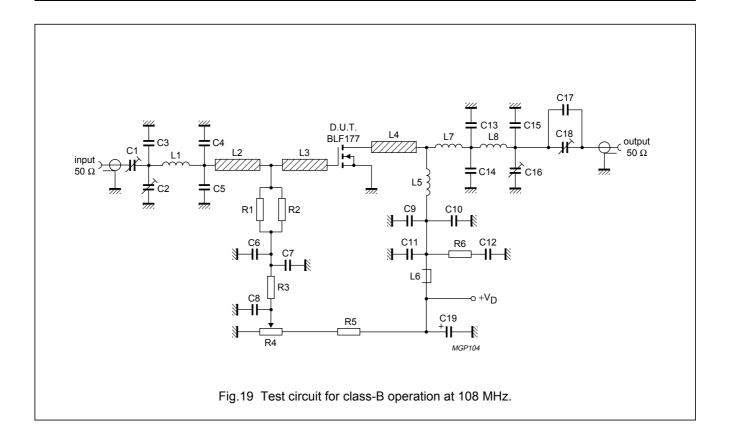
Fig.16 Power gain as a function of load power; typical values.



power; typical values.



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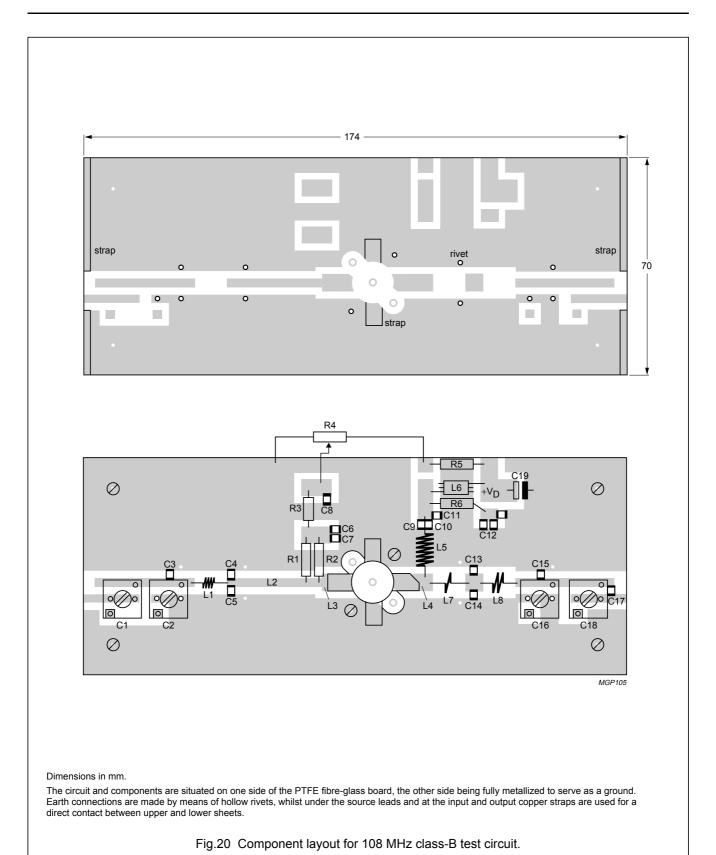
List of components class-B test circuit (see Fig.19)

COMPONENT	DESCRIPTION	VALUE	DIMENSIONS	CATALOGUE NO.
C1, C2, C16, C18	film dielectric trimmer	2.5 to 20 pF		2222 809 07004
C3	multilayer ceramic chip capacitor (note 1)	20 pF		
C4, C5	multilayer ceramic chip capacitor (note 1)	62 pF		
C6, C7, C9, C10	multilayer ceramic chip capacitor (note 1)	1 nF		
C8	multilayer ceramic chip capacitor	100 nF		2222 852 47104
C11	multilayer ceramic chip capacitor	10 nF		2222 852 47103
C12	multilayer ceramic chip capacitor	3 × 100 nF		2222 852 47104
C13, C14	multilayer ceramic chip capacitor (note 1)	36 pF		
C15	multilayer ceramic chip capacitor (note 1)	12 pF		
C17	multilayer ceramic chip capacitor (note 1)	5.6 pF		
C19	electrolytic capacitor	4.4 μF, 63 V		2222 030 28478
L1	3 turns enamelled 0.8 mm copper wire	22 nH	length 5.5 mm; int. dia. 3 mm; leads 2 × 5 mm	
L2	stripline (note 2)	64.7 Ω	31 × 3 mm	
L3, L4	stripline (note 2)	41.1 Ω	10 × 6 mm	
L5	6 turns enamelled 1.6 mm copper wire	122 nH	length 13.8 mm; int. dia. 6 mm; leads 2 × 5 mm	
L6	grade 3B Ferroxcube wideband HF choke			4312 020 36642
L7	1 turn enamelled 1.6 mm copper wire	16.5 nH	int. dia. 9 mm; leads 2 × 5 mm	
L8	2 turns enamelled 1.6 mm copper wire	34.4 nH	length 3.9 mm; int. dia. 6 mm; leads 2 × 5 mm	
R1, R2	metal film resistor	31.6 Ω, 1 W		
R3	metal film resistor	1 kΩ, 0.4 W		
R4	cermet potentiometer	5 kΩ		
R5	metal film resistor	44.2 kΩ, 0.4 W		
R6	metal film resistor	10 Ω, 1 W		

Notes

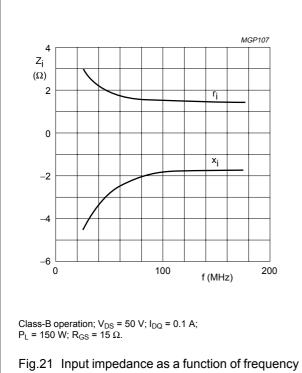
- 1. American Technical Ceramics (ATC) capacitor, type 100B or other capacitor of the same quality.
- 2. The striplines are on a double copper-clad printed circuit board, with PTFE fibre-glass dielectric (ϵ_r = 2.2), thickness 1.6 mm (Rogers 5880).

HF/VHF power MOS transistor

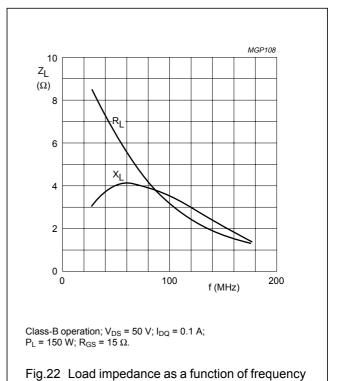


HF/VHF power MOS transistor

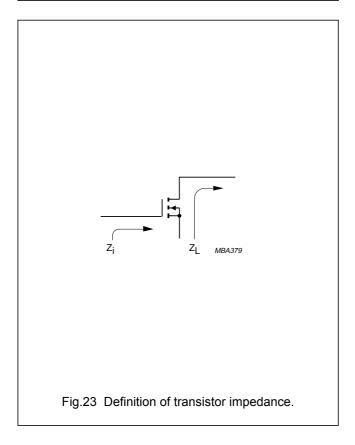
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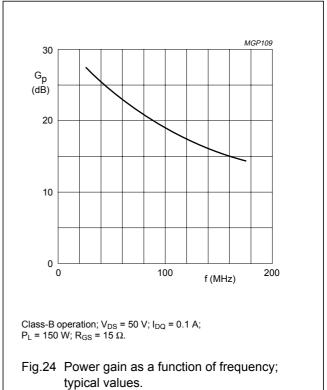


(series components); typical values.



(series components); typical values.





HF/VHF power MOS transistor

BLF177

BLF177 scattering parameters

 V_{DS} = 50 V; I_D = 100 mA; note 1.

f (MHz)	:	S ₁₁	s	21	s	12	s	22
1 (WIF12)	s ₁₁	∠Φ	s ₂₁	∠Φ	s ₁₂	∠Φ	s ₂₂	∠Φ
5	0.86	-110.20	36.90	114.20	0.02	25.20	0.64	-84.90
10	0.83	-139.40	20.39	93.30	0.02	5.10	0.55	-112.00
20	0.85	-155.70	9.82	72.60	0.02	-13.40	0.60	-129.30
30	0.88	-161.50	5.96	59.30	0.02	-24.70	0.69	-138.00
40	0.90	-164.90	3.98	49.30	0.02	-31.70	0.76	-144.30
50	0.92	-167.10	2.83	41.90	0.01	-35.80	0.82	-149.30
60	0.94	-169.00	2.11	36.00	0.01	-36.80	0.86	-153.50
70	0.96	-170.70	1.63	31.20	0.01	-33.70	0.89	-157.00
80	0.96	-172.20	1.29	27.40	0.00	-23.00	0.91	-159.90
90	0.97	-173.40	1.04	24.20	0.00	3.30	0.92	-162.40
100	0.97	-174.30	0.86	21.70	0.00	42.50	0.94	-164.50
125	0.99	-176.50	0.57	16.40	0.01	81.60	0.95	-168.80
150	0.99	-178.10	0.40	13.40	0.01	88.70	0.97	-171.90
175	0.99	-179.80	0.30	11.60	0.02	90.70	0.98	-174.50
200	1.00	179.20	0.23	11.00	0.02	90.80	0.98	-176.70
250	1.00	177.00	0.15	11.70	0.03	90.50	0.99	179.80
300	1.00	175.10	0.11	16.70	0.03	89.60	0.99	176.90
350	0.99	173.30	0.08	24.10	0.04	88.30	0.99	174.30
400	1.00	171.80	0.07	33.10	0.05	88.00	0.99	171.90
450	0.99	170.10	0.07	42.70	0.05	87.80	0.99	169.60
500	0.99	168.50	0.07	51.90	0.06	86.50	0.99	167.40
600	0.99	165.40	0.07	64.20	0.07	84.90	0.99	163.10
700	0.99	162.30	0.09	70.60	0.09	83.10	0.98	158.90
800	0.99	158.90	0.10	73.80	0.10	82.20	0.98	154.80
900	0.99	155.30	0.12	74.90	0.12	80.70	0.97	150.60
1000	0.98	151.80	0.14	76.40	0.14	79.80	0.97	146.20

Note

^{1.} For more extensive s-parameters see internet website: http://www.semiconductors.philips.com.markets/communications/wirelesscommunicationms/broadcast

HF/VHF power MOS transistor

0.229

0.219

0.243

0.006

0.004

0.506

0.496

0.505

0.495

0.105

0.095

1.120

1.005

0.130

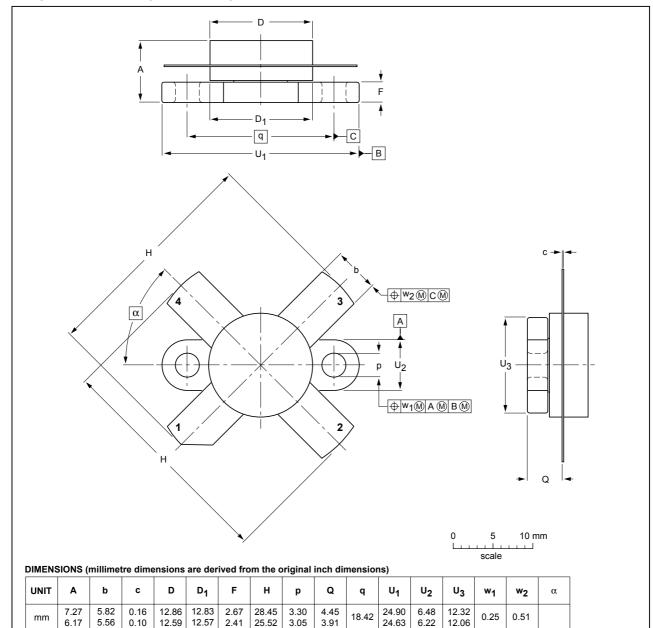
0.120

BLF177

PACKAGE OUTLINE

Flanged ceramic package; 2 mounting holes; 4 leads

SOT121B



OUTLINE		REFER	RENCES	EUROPEAN ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE		
SOT121B					99-03-29		

0.175

0.255

0.245

0.485

0.475

45°

0.02

AMPLEON BLF177

HF/VHF power MOS transistor

Legal information

Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.ampleon.com.

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BLF177#7

AMPLEON BLF177

HF/VHF power MOS transistor

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Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
BLF177#7	20150901	Product data sheet	-	BLF177_N_6			
Modifications:	The format of Ampleon.	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. 					
	 Legal texts h 	Legal texts have been adapted to the new company name where appropriate.					
BLF177_N_6	20070124	Product data sheet	-	BLF177_5			
BLF177_5	20041217	Product specification	-	BLF177_4			
(9397 750 14416)							
BLF177_4	20030721	Product specification	-	BLF177_3			
(9397 750 11579)							
BLF177_3	19980702	Product specification	-	BLF177_CNV_2			
(9397 750 04059)							
BLF177_CNV_2	19971216	Product specification	-	-			
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